

How To Order

15

J 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16

SERIES

1-AC Y1
2-AC Y2
3-CLASS I
4-CLASS II
5-CLASS III

FOOT TYPE

A-HIGH SEATED
S-STRAIGHT LEAD
O-OUTWARD KINK
I-INSIDE KINK
ASSEMBLY
F-UP/DOWN KINK
L-AXIAL
(FOR HIGH VOLTAGE)
≥40KVDC

N:RoHS
REACH
Low Halogen

COATING

D:DUREZ
E:EPOXY BLUE
Y:EPOXY
YELLOW

CAPACITANCE

0R5~0.5PF
010~1PF
100~10PF
101~100PF
102~1000PF
102~1nF
102~0.001 μ F
103~10000PF
103~10nF
103~0.01 μ F
104~100 n F
105~1 μ F
106~10 μ F

WORKING VOLTAGE

1C~16VDC
1E~25VDC
1H~50VDC
1J~63VDC
2A~100VDC
2E~250VDC
2G~400VDC
2H~500VDC
3A~1000VDC
3D~2000VDC
3E~2500VDC
3F~3000VDC
3G~4000VDC
3H~5000VDC
3J~6300VDC
(6000VDC)
3K~8000VDC
4A~10000VDC
4B~12000VDC
4C~15000VDC
4D~20000VDC
4E~25KVDC
4F~30KVDC
4G~40KVDC
4H~50KVDC
4J~63KVDC
4K~80KVDC
5A~100KVDC
5B~125KVDC
5C~160KVDC
5D~200KVDC
5E~250KVDC

FOOT LENGTH

3:3 mm ±1mm
4:4 mm ±1mm
5:5 mm ±1mm
7:7 mm ±1mm
8:8 mm ±1mm
0:10mm ±1mm
M:17mm ±2mm
L:25mm ±2mm
S:35mm ±2mm
X:50mm ±2mm
T:Taping ±2mm

PITCH±0.8mm

3:2.5mm
5:5.0mm
6:6.35mm
7:7.5mm
9:9.5(10) mm
1:12.5mm
4:15mm
2:20mm
H:OTHER(AXIAL
OR SPACIAL TYPE)

TOLERANCE

C=±0.25PF
D=±0.5PF
G=±2%
J=±5%
K=10%
M=±20%
Z=+80-20%

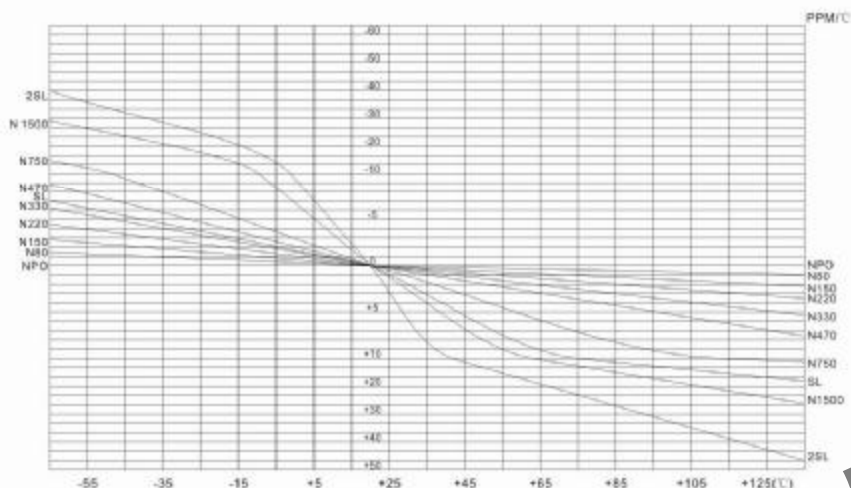
TEMPERATURE CHARACTERISTIC

NPO — NPO I
N75 — N750 I
SLO — SL I
2SL — 2SL I
X7R — X7R II
Y5E — Y5E II
Y5P — Y5P II III
Y5R — Y5R II
BNH — BN II
Y5T — Y5T II
Y5U — Y5U II III
Y5V — Y5V II III
Z5U — Z5U II
Z5V — Z5V II

溫度特性曲線圖 Capacitance and Temperature Curve

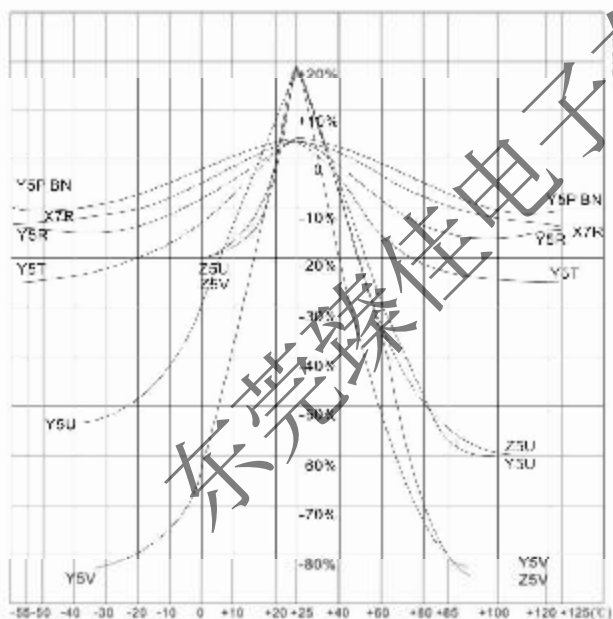
15

T.C.: Temperature compensating ceramic disc capacitors
溫度補償型陶瓷電容器 (Class I)



HK: High permittivity ceramic disc capacitors 高誘電型陶瓷電容器 (Class II)

S.C: Semi-conductive ceramic disc capacitors 半導體型陶瓷電容器 (Class III)



Temperature Coefficient:

Code	T.R.	PPM/°C	EIA Code	Code	T.R.	Cap change	EIA Code	Code	T.R.	Cap Change	EIA code
CH	-55°C ~ 125°C	0±60~500	COH(NPO)	B	-25°C ~ +125°C	±15%	Y5R	B	-55°C ~ +125°C	±15%	X7R
UJ	-55°C ~ 125°C	-750±120	U2J(N750)	B	-25°C ~ +125°C	±10%	Y5P BN	B	-25°C ~ +125°C	±22%	Y5T
SL	-55°C ~ 125°C	+350~-1000	S2L	E	+10°C ~ +85°C	+22%~-56%	Z5U	E	-25°C ~ +125°C	+22%~-56%	Y5U
2SL	-55°C ~ 125°C	+2000~-5000	2SL	F	+10°C ~ +85°C	+22%~-82%	Z5V	F	-25°C ~ +85°C	+22%~-82%	Y5V

特 性

CHARACTERISTICS

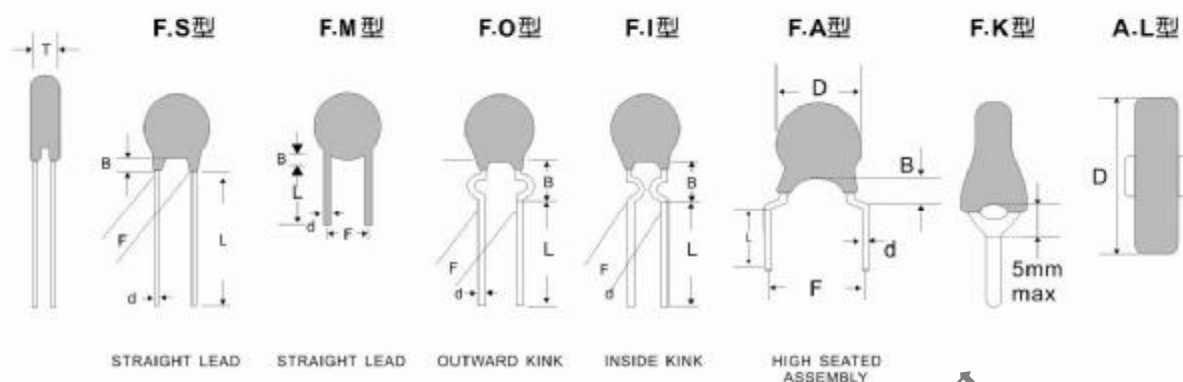
項目 ITEM	規格 SPECIFICATION		檢測方法及條件 TEST METHOD AND CONDITION
1. 外觀、尺寸、標誌 Appearance, size and mark	無異常 Normal		依外觀、尺寸及標誌標準，尺寸用游標卡尺檢查、外觀、標誌用目視法檢驗； According to the standard of appearance, size and mark, size measured by vernier, appearance and marks test by visual.
2. 絕緣電阻 Insulation resistance	T.C.	10000MΩMIN	端子間施加額定電壓，500VDC以上，以500VDC測定，測定時間為60秒以上。 Apply rated voltage. Above 500vdc rated voltage tested by 500vdc, Min.charged 60 seconds.
	HIK	5000MΩMIN	
	半導體 (S.C.)	100MΩ MIN	
3. 耐電壓 Voltage proof	無破裂等明顯損壞異狀 No failure		端子間加工作電壓施壓1-5秒，充放電電流為50mA以下。 電壓測試完後需存放於25℃的環境下，放置96hrs後方能測試其容量。 Applied as following T.V. 1-5s between terminal and less than 50mA current. Capacitor shall be measured capacitance after leaving for 96hrs at 25℃ W.V. < 500VDC T.V. = 200% x W.V W.V. < 1KVDC T.V. = 150% x W.V W.V < 2KVDC T.V. = 125% x W.V (FOR DUREZ) (EPOXY IN P9)
4. 靜電電容 Capacitance	在標準允許誤差內 Within the specified tolerance		使用頻率 (Test frequency): T.C.: 1000PF 1MHz 1000PF 1KHz HIK, 半導體類 (S.C.) 1KHz 使用電壓 (Test voltage): T.C, HIK, 1.0 ± 0.2Vrms S.C. 0.1Vrms 使用溫度 (Temperature): 25℃ ± 2℃
5. Q 值和 散逸因素 Q AND DF	T.C.: ① C<30PF: Q>400+20xC ② C>30PF: Q>1000		測定條件同靜電容量之規定。 same condition as the capacitance
	HIK: ①Y5E, Y5P, Z5U, Y5U, X7R: DF<2.5% ②Z5V, Y5V: DF<5% ③BN, Y5T: DF<0.5%, Y5R: DF<0.2% (Low Loss, Non RoHS)		
	半導體類 (S.C.): ①Y5P, Y5U: DF<5% ②Y5V, DF: <7%		
6. 溫度特性 Temperature characteristic (T.C.)	T.C.: C<4PF TC±250PPM/℃ C<9PF TC±120PPM/℃ C<10PF TC±60PPM/℃ SL TC R350-N1000		試驗步驟見下表: Test temperature
	HIK, S.C.: Y5E: ±4.7% Y5P, BN: ±10% X7R, Y5R: ±15% Y5T: ±22% Y5U, Z5U: +22%-56% Y5V, Z5V: +22%-82%		溫度特性容量變化率的計算公式見下表 T.C. calculated by under formula ① T.C.: (PPM) $T.C. = \frac{C_2 - C_1}{C_1(T_2 - T_1)} \times 10^6$ ② HIK, S.C.: $T.C. = \frac{C_2 - C_1}{C_1} \times 100\%$
7. 焊錫附著 性及焊錫 耐熱性 Resistance to solder heat and Solder ability of leads	外觀 Appearance	引線周圍至少75%的面積均勻附錫，且本體無破裂等損壞現象。 Lead wire shall be soldered with uniformly coated on the axial direction over 75% of the circumferential direction, and no defect.	

項目 ITEM	規格 SPECIFICATION		檢測方法及條件 TEST METHOD AND CONDITION															
7. 焊錫附着性及焊錫耐熱性 Resistance to solder heat and Solder ability of leads	靜電容量 變化率 Capacitance Change	T.C.: $\pm 5\%$ or $\pm 0.5PF$ HIK, S.C.: Y5E, Y5P, BN: $\pm 10\%$ X7R, Y5R: $\pm 15\%$ Y5T, Y5U, Z5U: $\pm 20\%$ Z5V, Y5V: $\pm 30\%$	將元件端子線浸入 $260^{\circ}\text{C} \pm 5^{\circ}\text{C}$ 的溶錫內，端子線浸至離本體邊緣 $2.0-3.0\text{mm}$ 處，并保持 $3+1/-0$ 秒。 試驗前，將元件放置 $85+3/-0^{\circ}\text{C}$ 中預熱，5分鐘後再進行焊錫試驗；試驗後，元件須放置室溫中24小時後方可進行電氣特性的測試。 The lead wire shall be immersed into the melted solder of $260^{\circ}\text{C} \pm 5^{\circ}\text{C}$ up to about 2.0 to 3.0 mm from the main body for $3+1/-1$ seconds.. Capacitor shall be measured after leaving for 24 hours at room temperature.															
	Q OR DF	T.C.: ① $C < 30PF$: $Q \geq 400+20 \times C$ ② $C \geq 30PF$: $Q \geq 1000$																
		HIK: ① Y5E, Y5P, X7R, Z5U, Y5U: $DF \leq 2.5\%$ ② Z5V, Y5V: $DF \leq 5\%$ ③ BN, Y5T: $DF \leq 0.5\%$, Y5R: $DF \leq 0.2\%$																
		S.C.: ① Y5P, Y5U: $DF \leq 5\%$ ② Y5V: $Df \leq 7\%$																
	絕緣電阻 Insulation Resistance	T.C.: $10000M \Omega \text{ min}$ HIK: $5000M \Omega \text{ min}$ S.C.: $100M \Omega \text{ min}$																
8. 溫度循環 Temp. Cycle	外觀 Appearance	無缺陷 No marked defect	將電容器進行如下五個溫度循環試驗： Capacitor shall be subjected to five cycles of the temperature cycle as following: <table><tr><th>Step</th><th>Temp.($^{\circ}\text{C}$)</th><th>Time</th></tr><tr><td>1</td><td>Min rated temp(+0-3)</td><td>30min</td></tr><tr><td>2</td><td>25</td><td>30min</td></tr><tr><td>3</td><td>Max rated temp(+0-3)</td><td>30min</td></tr><tr><td>4</td><td>25</td><td>30min</td></tr></table> 放置室溫下一段時間再測量其電氣特性： Measure at room temperature after cooling for: T.C.: 24Hr HIK, S.C.: 48Hr	Step	Temp.($^{\circ}\text{C}$)	Time	1	Min rated temp(+0-3)	30min	2	25	30min	3	Max rated temp(+0-3)	30min	4	25	30min
	Step	Temp.($^{\circ}\text{C}$)		Time														
	1	Min rated temp(+0-3)		30min														
	2	25		30min														
	3	Max rated temp(+0-3)		30min														
4	25	30min																
靜電容量 Capacitance	T.C.: $\pm 5\%$ or $\pm 0.5PF \text{ max.}$ HIK, (S.C.): Y5E, Y5P, BN: $\pm 10\%$; X7R, Y5R: $\pm 15\%$; Y5T, Y5U, Z5U: $\pm 20\%$; Z5V, Y5V: $\pm 30\%$.																	
Q OR DF	T.C.: $C < 30PF$: $Q \geq 400+20 \times C$ $C \geq 30PF$: $Q \geq 1000$ HIK Y5E, Y5P, X7R, Y5U, Z5U $DF \leq 5\%$ Y5V, Z5V $DF \leq 7.5\%$ BN, Y5T $DF \leq 1\%$ Y5R $DF \leq 0.5\%$ S.C. Y5P, Y5U $DF \leq 7.5\%$ Y5V $DF \leq 10\%$																	
	與初始值相等 To satisfy the specified initial value																	
絕緣電阻 Insulation Resistance	與初始值相等 To satisfy the specified initial value																	
9. 耐濕負荷 Humidity loading	外觀 Appearance	無顯著之異常現象 No marked defect	在溫度 $40 (\pm 2^{\circ}\text{C})$ 、相對濕度95%的狀態下，連續施加直流額定電壓（充放電電流為50mA以下）500 (+24-0) 小時； 試驗後置于室溫中： T.C.類規格需放置24小時以上方可測定其電氣特性； HIK、半導體類規格需放置48小時以上方可測定其電氣特性。 Apply rated voltage for 500 (+24-0) hours at $40 (\pm 2^{\circ}\text{C})$ in 95% RH Charge and discharge current 50mA max. Leave the capacitors in ambient condition for over the following time. Measurement T.C.: 24Hrs HIK, S.C.: 48Hrs															
	靜電容量 變化率 Capacitance Change	T.C.: $\pm 7.5\%$ or $\pm 0.75PF \text{ max.}$ HIK、半導體類 (S.C.): Y5E, Y5P, BN: $\pm 15\%$ X7R, Y5R: $\pm 20\%$ Y5T, Y5U, Z5U: $\pm 25\%$ Z5V, Y5V: $\pm 35\%$																
	Q OR DF	T.C.: ① $C < 10PF$: $Q \geq 200+10 \times C$ ② $10PF \leq C < 30PF$: $Q \geq 275+2.5 \times C$ ③ $C \geq 30PF$: $Q \geq 350$ HIK: Y5E, Y5P, X7R, Y5U, Z5U $DF \leq 5\%$ Y5V, Z5V $DF \leq 7.5\%$ BN, Y5T $DF \leq 1\%$ Y5R $DF \leq 0.5\%$ 半導體類 (S.C.): Y5P, Y5U $DF \leq 7.5\%$ Y5V $Df \leq 10\%$																
		絕緣電阻 Insulation resistance		$500M \Omega \text{ min. or}$ $25M \Omega \text{ XUF min.}$														

項目 ITEM	規格 SPECIFICATION		檢測方法及條件 TEST METHOD AND CONDITION
10. 高溫負荷 (壽命試驗) High temperature Loading (Loading life)	外觀 Appearance	無顯著之異常。 No marked defect.	<500VDC在試驗溫度下連續施加2倍W.V. ≥ 500VDC,在試驗溫度下連續施加1倍W.V.(充放電電流50mA以下)1000(+48-0)小時
		T.C.: ±7.5% or ±0.75PF;	
	靜電容量 變化率 Capacitance change	HIK、半導體類(S.C.): Y5E、Y5P、BN:±10%; X7R、Y5R:±15%; Y5T、Y5U、Z5U:±20%; Z5V、Y5V:±30%。	<500VDC apply 2 times rated voltage, ≥ 500VDC apply 1 times rated voltage, at maximum operating temperature for 1000(+48-0)hours
	Q or DF	T.C. C<30PF; Q≥200+10xC C≥30PF: Q≥500	Test temp.: T.C., Y5E、Y5P、BN、Y5R、Y5T、Y5U、Z5U、Y5V、Z5V: 85℃±5℃ NPO N750、X7R: 125℃±5℃ Change or discharge current shall not exceed 50mA..
		HIK. Y5E、Y5P、X7R、Y5U、Z5U DF≤5% Y5V、Z5V DF≤7.5% BN、Y5T DF≤1% Y5R DF≤0.5%	試驗後：取出於室溫中，T.C.類需放置24小時以上方可測定；HIK、半導體類需放置48小時以上方可測定。 Capacitor shall be measured after leaving at room temperature T.C.: 24Hr HIK: S.C.: 48Hr
		半導體 (S.C.): Y5P、Y5U DF≤7.5% Y5V Df≤10%	
絕緣電阻 Insulation resistance	T.C.:1000MΩ min HIK:500MΩ min S.C.:25MΩ x U.F min		
11. 端子強度 Strength of lead	抗拉強度 Pull	導線不斷裂，電容器本體不破損。 Lead wire shall not cut off and capacitor shall not be broken.	垂直固定被測物本體，引線向下，負荷施力方向為端線引出方向。施加負荷為1.0kg，時間為5秒 As a figure fix the body of capacitor, apply a tensile weight gradually to each lead in the radial direction of capacitor up to 1.0kg, and keep it for 5 secretary..
	彎曲強度 Bending		固定被測物，施加0.5kg於端子引線端并彎曲90°，回復原來之位置，并反向彎曲90°，1次彎曲時間為5秒。 Each lead wire shall be subjected to 0.5kg weight and then a 90° bent, in one direction, return to original position and then a 90° bent in the opposite direction at the rate of one bent in 5 seconds..
11. 儲存 Storage	必須存放于室溫5-35℃中且濕度≤75%的室內，在此儲存條件下可保證3年的壽命。 Store all capacitors indoors at temperature of 5-35℃, humidity≤75%. They are warranted for a period of 3 years from the date of manufacture.		

WV	CLASS I		CLASS II			
	NPO	SL/2SL	X7R	Y5P(Y5E)	Y5U	Y5V/Z5V
25V (1E)	0.5~50PF 51~121 151~221 241~391	24~181PF 201~331 361~681 821~102	821~152 182~472 502~882 103	201~222 242~472 472~103	202~682 822~103	222~103 103~223
50V (1H)	0.5~50 51~121 151~221 241~391	24~181 201~331 361~681 821~102	821~152 182~472 502~822 103	201~222 242~472 472~103	202~682 822~103	222~103 103~223
100V (2A)	0.5~50 51~121 151~221 241~391	24~181 201~331 361~681 821~102	827~152 182~472 502~822 103	201~222 242~472 472~103	202~682 822~103	222~103 103~223
250V (2E)	0.5~50 51~121 151~221 241~391	24~181 201~331 361~681 821~102	821~152 182~472 502~822 103	201~222 242~472 472~103	202~682 822~103	222~103 103~223 333 473 104
500V (2H)	0.5~50 51~121 151~221 241~391	24~181 201~331 361~681 821~102	471~102 122~222 242~472 502~682 822 103	151~122 152~272 302~472 502~682 822~103	102~222 332~682 682~103 103	102~332 362~682 682~103 103~223 473~683 104
1KV (3A)	0.5~50 51~121 151~221 241~391	20~101 101~181 201~271 301~391 471~561 681 821~102	331~102 122~202 222~392 472~562 682 822 103	101~102 102~222 222~332 362~472 502~682 822 103	822~222 222~472 472~682 822~103	152~332 332~682 822~103

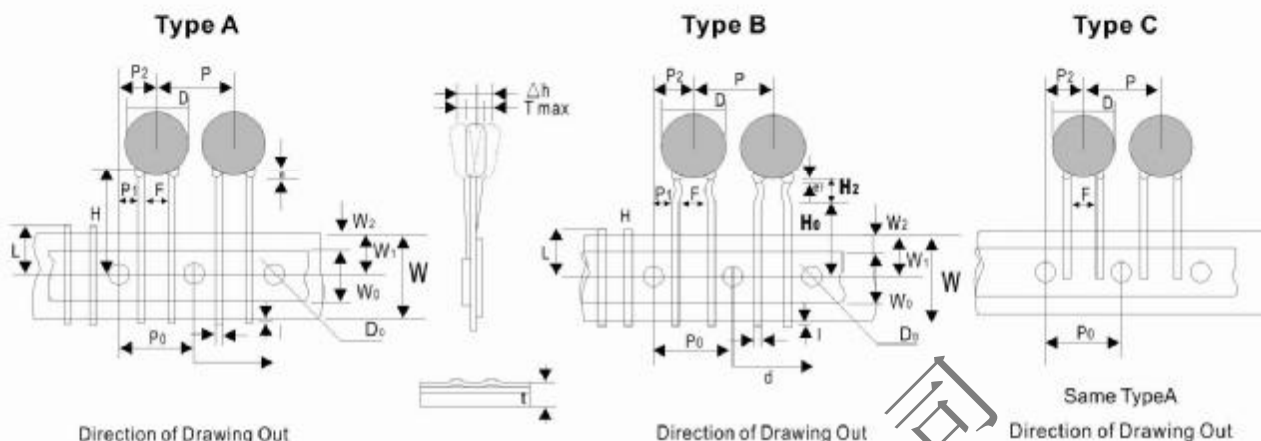
WV	CLASS III			D (MAX)	T (MAX)	P (±0.8)	D (±0.1)
	S.C.Y5P	S.C.Y5U	S.C.Y5V				
25V (1E)	472~223 333~473 563~683 104	153~473 683~104 104~224	103~473 183~154 104~224	6 8 10 12	3 3 3 3	2.5/5.0 2.5/5.0 5.0/7.5/10 5.0/7.5/10	0.45 0.45 0.45 0.45
50V (1H)	472~223 333~473 563~683 104	153~473 683~104 104~224	103~473 503~104 104~224	6 8 10 12	3 3 3 3	2.5/5.0 2.5/5.0 5.0/7.5/10 5.0/7.5/10	0.45 0.45 0.45 0.45
100V (2A)	472~223 333~473 563~683 104	153~473 683~104 104~154 154~224	103~473 503~104 104~224 204~224	6 8 10 12	3 3 3 3	2.5/5.0 2.5/5.0 5.0/7.5/10 5.0/7.5/10	0.45 0.45 0.45 0.45
250V (2E)		153~333 473~104	103~473 503~104 104~224	6 8 10 12 14 16	3 3 3 3 3 3	2.5/5.0 2.5/5.0 5.0/7.5/10 5.0/7.5/10 7.5/10 7.5/10	0.45 0.45 0.45 0.45 0.5 0.5
500V (2H)				6 8 10 12 14 16	3 3 3 3 3 3	5.0 5.0/7.5 5.0/7.5/10 5.0/7.5/10 7.5/10 7.5/10	0.45 0.45 0.45 0.5 0.5 0.5
1KV (3A)				6 8 10 12 14 16 18	3 3 3 3 3 3 3	5.0 5.0/7.5 5.0/7.5/10 5.0/7.5/10 7.5/10 10 10	0.45 0.45 0.45 0.5 0.5 0.5 0.6



MODEL	Working Voltage	T (mm) (max)	d (mm) ± 0.1	L (mm)	F (mm)	B (mm) (max)
F S	12~25	3	0.45~1.0	3~50	2.5 $^{+1}_{-0.5}$ /5.0 ± 0.8	2
	50~100	3			2.5 $^{+1}_{-0.5}$ /5.0 ± 0.8	2
	500	3			5.0 ± 0.8	3
	1KV~3KV	5			5.0/6.35/7.5 ± 0.8	3
	3KV~UP	20			7.5/10/12.5/15/20 ± 1	3
F A	12~25	3	0.45~1.0	3~50	2.5 $^{+1}_{-0.5}$ /5.0 ± 0.8	2
	50~100	3			2.5 $^{+1}_{-0.5}$ /5.0 ± 0.8	2
	500	3			5.0 ± 0.8	3
	1KV~3KV	5			5.0/6.35/7.5 ± 0.8	3
	3KV~20KV	10			10 ± 1	3
F O	12~25	3	0.45~0.8	3~50	5.0 ± 0.8	5
	50~100	3			5.0 ± 0.8	5
	500	3			5.0 ± 0.8	5
	1KV~3KV	5			5.0/6.35/7.5 ± 0.8	5
	3KV~20KV	10			5/7.5/10 ± 1	5
F I	12~25	3	0.45~0.8	3~50	5.0 ± 0.8	5
	50~100	3			5.0 ± 0.8	5
	500	3			5.0 ± 0.8	5
	1KV~3KV	5			5.0/6.35/7.5 ± 0.8	5
	3KV~6.3KV	8			7.5/10 ± 1	5
F K	1KV~3KV	5	0.45~0.8	3~50	5.0/6.35/7.5 ± 0.8	5
	3KV~30KV	13			5/7.5/10 ± 1	5
A L	10KV~250KV	40				

CLASS 1,2,3/TAPING SPECIFICATIONS

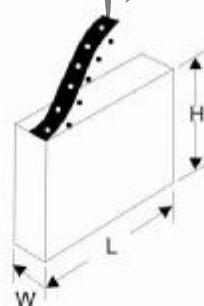
Taping(Radial)



(Unit:mm)

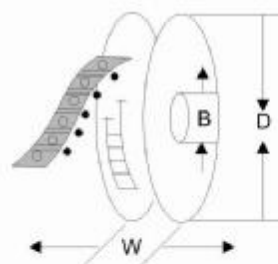
Item	Code	Dimensions(mm)	Item	Code	Dimensions(mm)
Taping Pitch	P	$12.7 \pm 1.0 / 25.4 \pm 1.0$	Lead Protrusion	l	$+0.5 \sim 1.0$
Guide Pitch	P ₀	$12.7 \pm 1.0 / 25.4 \pm 1.0$	Diameter of Feed Hole	D ₀	4.0 ± 0.3
Lead Spacing	F	2.5/3.0/3.5/7.5/ 10/12.5/15 ± 0.8	Diameter of Lead	d	$0.50 \sim 0.8 \pm 0.1$
Feed Hold Position Capacitor Body	P ₂	6.35 ± 1.3 for F=5.25	Total Thickness of Tape	t	0.7 ± 0.3
Feed Hold Position Capacitor Lead	P ₁	3.85 ± 0.7 for F=5.25	Thickness of Capacitor Body	T	< 7
Diameter of Disc	D	See table of each series	Alignment to ER Direction	Δh	$T \pm 2.0$
			Length of Snipped Lead	L	$11.0^{+0}_{-0.1}$
Width of Base Tape	W	18.0 ± 0.5	Width of Hold-down Tape	W ₀	$6.0 \sim 15$
Feed Hole Vertical Position	W ₁	$9.10^{+0.75}_{-0.5}$	Hold-down Tape Position	W ₂	1.5 ± 1.5
Taping Height	For Crimp	18 ± 2	Coating Extension	e	1.5
	For Straight	16.0 ± 1.0	Coating Extension	eI	Up to center of crimp

AMMO PACK



- $H=241 \pm 5\text{mm}$
- $L=332 \pm 5\text{mm}$
- $W=42 \pm 3\text{mm}$

REEL



- $D \leq 354(13.93)$
- $B \leq 21(.83")$ or $\leq 30(1.18")$
- $W \leq 65(2.56)$